

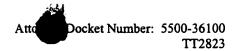
As a below named inventor, I hereby declare that:

My residence, post office address, and citizenship are as stated below next to my name.

I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled "ULTRATHIN HIGH-K GATE DIELECTRIC WITH FAVORABLE INTERFACE PROPERTIES FOR IMPROVED SEMICONDUCTOR DEVICE PERFORMANCE," the specification of which:

is attached hereto.		aton Contol No.			
was filed onand was amended on	as Application Serial No (if applicable).				
	,	••			
I hereby state that I have re including the claims, as amended by an			ve-identified	specification,	
I acknowledge the duty to dis material to patentability of the subject 1.56.					
I hereby claim foreign prio application(s) for patent or inventor's c listed below designating least one cou foreign application for patent or inven before that of the application on which	ertificate listed below, or ntry other than the Unite tor's certificate, or of an	under § 365(a) of any PC d States of America, and	CT internation I have identifi	al application ed below any	
Prior Foreign Application No.	Country	Filing Date (mm/dd/yy)	Priority Claimed	Cert. copy Attached	
N/A					
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I hereby claim the benefit unbelow.	der 35 U.S.C. § 119(e) (of any United States prov	isional applic	ation(s) listed	
Provisional Application No.	Filing Date (mm/dd/yy)				
N/A					
		XI 1 0 1 1 1	- () 1: . 11	1	
I hereby claim the benefit unc § 365(c) of any PCT international applied the subject matter of each of the clainternational application in the manner disclose all information known to mapplication, as "materiality" is defined prior application and the national or PC	lication listed below desi ims of this application provided by the first par e to be material to the i in 37 C.F.R. § 1.56, w.	gnating the United States is not disclosed in the pagraph of 35 U.S.C. § 112 patentability of the subjaich became available be	of America, a prior United S 2, I acknowled ject matter cl	and, insofar as States or PCT lge the duty to aimed in this	
Parent Application No.	Filing Date (mm/dd/yy)	Parent Patent No. (if a	pplicable) or	Status	
N/A					





I hereby revoke any previous Powers of Attorney and appoint

Elizabeth A. Apperley	Reg. No. 36,428
Paul S. Drake	Reg. No. 33,491
Louise K. Miller	Reg. No. 36,609
Vincenzo D. Pitruzzella	Reg. No. 28,656
Louis A. Riley	Reg. No. 39,817
Richard J. Roddy	Reg. No. 27,688
J. Vincent Tortolano	Reg. No. 31,433
Rita M. Wisor	Reg. No. 41,382
William D. Zahrt II	Reg. No. 26,070

each said attorneys or agents being employed by Advanced Micro Devices, Inc.; and

Darryl J. Adams	Reg. No. 41,424
Mark L. Berrier	Reg. No. 35,066
Dan R. Christen	Reg. No. 39,943
Timothy S. Corder	Reg. No. 38,414
Kevin L. Daffer	Reg. No. 34,146
Jeffrey C. Hood	Reg. No. 35,198
B. Noël Kivlin	Reg. No. 33,929
Robert C. Kowert	Reg. No. 39,255
Lawrence J. Merkel	Reg. No. 41,191
Eric B. Meyertons	Reg. No. 34,876
Eric A. Stephenson	Reg. No. 38,321
David A. Rose	Reg. No. 26,223

each said attorneys or agents being members or associates of the firm of Conley, Rose & Tayon, P.C., as attorney or agent for so long as they remain with such company or firm, with full power of substitution and revocation, to prosecute the application, to make alterations and amendments therein, to transact all business in the Patent and Trademark Office in connection therewith, and to receive the Letters Patent:

Please direct all communications to:

Kevin L. Daffer Conley, Rose & Tayon, P.C. P.O. Box 398 Austin, Texas 78767-0398 Phone: (512) 476-1400

I hereby declare that all statements made herein of my own knowledge are true and that all statements made herein on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under 18 U.S.C. § 1001 and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

Inventor's Full Name:	Mark I. Gardner				
Inventor's Signature:			Date:		
City and State (or Foreign Country) or	f Residence:	Cedar Creek, TX	_ Citizenship:	U.S.A.	
Post Office and Residence Address:	Idress: P.O. Box 249, Highway 535, Cedar Creek, TX 78612 (Include number, street name, city, state and zip code)				

Â)	
Att	Docket Number:	5500-3610
		TT282

Inventor's Full Name:	1 1	Dim-Lee Kwong	3	
Inventor's Signature:	Mle	-7	Date:	2-3-98
City and State (or Foreign	Country) of Residence:	Austin, TX	Citizenship:	U.S.A.
Post Office and Residence		10225 Open Gate Dr.,		
	(Include numbe	er, street name, city, stat	e and zip code)	
Inventor's Full Name:		H. Jim Fulford, J	r	
Inventor's Signature:			Date:	
City and State (or Foreign	Country) of Residence:	Austin, TX	Citizenship:	U.S.A.
Post Office and Residence		9808 Woodshire Dr.,		
	(Include numbe	er, street name, city, stat	e and zip code)	





DECLARATION AND POWER OF ATTORNEY

As a below named inventor, I hereby declare that:

My residence, post office address, and citizenship are as stated below next to my name.

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Parent Application No.	Filing Date (mm/dd/yy)	Parent Patent No. (if	applicable) or	Status
N/A				





Docket Number: 5500-36100

I hereby revoke any previous Powers of Attorney and appoint

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Inventor's Full Name:	Mark I. Gardner				
Inventor's Signature:	Mad	6	Sady	Date://_	20/98
City and State (or Foreign	1 Country) of Resider	nce:	Cedar Creek, TX	Citizenship:	U.S.A.
Post Office and Residence	e Address:	P.O. I	30x 249, Highway 535,	Cedar Creek, TX 7	8612
	(Includ	le numbe	r street name city state	and zin code)	





Inventor's Full Name:		Dim-Lee Kwong		
Inventor's Signature:			Date:	
City and State (or Foreign Country)	of Residence:	Austin, TX	Citizenship:	U.S.A.
Post Office and Residence Address:		10225 Open Gate Dr., A		
	(Include nun	nber, street name, city, state a	nd zip code)	
Inventor's Full Name:		H. Jim Fulford, Jr.		
Inventor's Signature:	5/ Ji	The la	Date: 16	/20/98
City and State (or Foreign Country)	of Residence:	Austin, TX	Citizenship:	U.S.A.
Post Office and Residence Address:		9808 Woodshire Dr., Au		
	(Include nun	nber, street name, city, state a	nd zip code)	